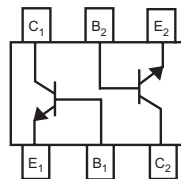
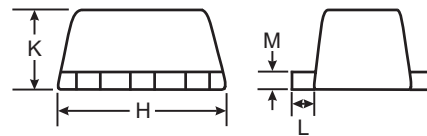
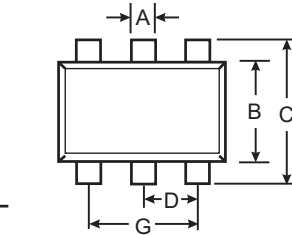


### Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (MMDT2907V)
- Ultra-Small Surface Mount Package
- **Lead Free By Design/RoHS Compliant (Note 1)**
- **"Green" Device (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**

### Mechanical Data

- Case: SOT-563, Molded Plastic
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Finish — Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Polarity: See Diagrams Below
- Marking & Type Code Information: See Last Page
- Ordering Information: See Last Page
- Weight: 0.003 grams (approx.)



| SOT-563              |      |      |      |
|----------------------|------|------|------|
| Dim                  | Min  | Max  | Typ  |
| A                    | 0.15 | 0.30 | 0.25 |
| B                    | 1.10 | 1.25 | 1.20 |
| C                    | 1.55 | 1.70 | 1.60 |
| D                    | 0.50 |      |      |
| G                    | 0.90 | 1.10 | 1.00 |
| H                    | 1.50 | 1.70 | 1.60 |
| K                    | 0.56 | 0.60 | 0.60 |
| L                    | 0.10 | 0.30 | 0.20 |
| M                    | 0.10 | 0.18 | —    |
| All Dimensions in mm |      |      |      |

### Maximum Ratings @ T<sub>A</sub> = 25°C unless otherwise specified

| Characteristic                              | Symbol                            | Value       | Unit |
|---------------------------------------------|-----------------------------------|-------------|------|
| Collector-Base Voltage                      | V <sub>CBO</sub>                  | 75          | V    |
| Collector-Emitter Voltage                   | V <sub>CEO</sub>                  | 40          | V    |
| Emitter-Base Voltage                        | V <sub>EBO</sub>                  | 6.0         | V    |
| Collector Current - Continuous              | I <sub>C</sub>                    | 600         | mA   |
| Operating and Storage and Temperature Range | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150 | °C   |

### Thermal Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

| Characteristic                                   | Symbol           | Value | Unit |
|--------------------------------------------------|------------------|-------|------|
| Total Power Dissipation (Note 3)                 | P <sub>d</sub>   | 150   | mW   |
| Thermal Resistance, Junction to Ambient (Note 3) | R <sub>θJA</sub> | 833   | °C/W |

- Notes:
1. No purposefully added lead.
  2. Diodes Inc.'s "Green" policy can be found on our website at [http://www.diodes.com/products/lead\\_free/index.php](http://www.diodes.com/products/lead_free/index.php).
  3. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.

**Electrical Characteristics** @  $T_A = 25^\circ\text{C}$  unless otherwise specified

| Characteristic                       | Symbol        | Min                                     | Max                               | Unit                | Test Condition                                                                                                                                                                                                                                                                                                                                                            |
|--------------------------------------|---------------|-----------------------------------------|-----------------------------------|---------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>OFF CHARACTERISTICS (Note 4)</b>  |               |                                         |                                   |                     |                                                                                                                                                                                                                                                                                                                                                                           |
| Collector-Base Breakdown Voltage     | $V_{(BR)CBO}$ | 75                                      | —                                 | V                   | $I_C = 10\mu\text{A}$ , $I_E = 0$                                                                                                                                                                                                                                                                                                                                         |
| Collector-Emitter Breakdown Voltage  | $V_{(BR)CEO}$ | 40                                      | —                                 | V                   | $I_C = 10\text{mA}$ , $I_B = 0$                                                                                                                                                                                                                                                                                                                                           |
| Emitter-Base Breakdown Voltage       | $V_{(BR)EBO}$ | 6.0                                     | —                                 | V                   | $I_E = 10\mu\text{A}$ , $I_C = 0$                                                                                                                                                                                                                                                                                                                                         |
| Collector Cutoff Current             | $I_{CBO}$     | —                                       | 10                                | nA<br>$\mu\text{A}$ | $V_{CB} = 60\text{V}$ , $I_E = 0$<br>$V_{CB} = 60\text{V}$ , $I_E = 0$ , $T_A = 150^\circ\text{C}$                                                                                                                                                                                                                                                                        |
| Collector Cutoff Current             | $I_{CEX}$     | —                                       | 10                                | nA                  | $V_{CE} = 60\text{V}$ , $V_{EB(OFF)} = 3.0\text{V}$                                                                                                                                                                                                                                                                                                                       |
| Emitter Cutoff Current               | $I_{EBO}$     | —                                       | 10                                | nA                  | $V_{EB} = 3.0\text{V}$ , $I_C = 0$                                                                                                                                                                                                                                                                                                                                        |
| Base Cutoff Current                  | $I_{BL}$      | —                                       | 20                                | nA                  | $V_{CE} = 60\text{V}$ , $V_{EB(OFF)} = 3.0\text{V}$                                                                                                                                                                                                                                                                                                                       |
| <b>ON CHARACTERISTICS (Note 4)</b>   |               |                                         |                                   |                     |                                                                                                                                                                                                                                                                                                                                                                           |
| DC Current Gain                      | $h_{FE}$      | 35<br>50<br>75<br>100<br>40<br>50<br>35 | —<br>—<br>—<br>300<br>—<br>—<br>— | —                   | $I_C = 100\mu\text{A}$ , $V_{CE} = 10\text{V}$<br>$I_C = 1.0\text{mA}$ , $V_{CE} = 10\text{V}$<br>$I_C = 10\text{mA}$ , $V_{CE} = 10\text{V}$<br>$I_C = 150\text{mA}$ , $V_{CE} = 10\text{V}$<br>$I_C = 500\text{mA}$ , $V_{CE} = 10\text{V}$<br>$I_C = 10\text{mA}$ , $V_{CE} = 10\text{V}$ , $T_A = -55^\circ\text{C}$<br>$I_C = 150\text{mA}$ , $V_{CE} = 1.0\text{V}$ |
| Collector-Emitter Saturation Voltage | $V_{CE(SAT)}$ | —                                       | 0.3<br>1.0                        | V                   | $I_C = 150\text{mA}$ , $I_B = 15\text{mA}$<br>$I_C = 500\text{mA}$ , $I_B = 50\text{mA}$                                                                                                                                                                                                                                                                                  |
| Base-Emitter Saturation Voltage      | $V_{BE(SAT)}$ | 0.6<br>—                                | 1.2<br>2.0                        | V                   | $I_C = 150\text{mA}$ , $I_B = 15\text{mA}$<br>$I_C = 500\text{mA}$ , $I_B = 50\text{mA}$                                                                                                                                                                                                                                                                                  |
| <b>SMALL SIGNAL CHARACTERISTICS</b>  |               |                                         |                                   |                     |                                                                                                                                                                                                                                                                                                                                                                           |
| Output Capacitance                   | $C_{obo}$     | —                                       | 8                                 | pF                  | $V_{CB} = 10\text{V}$ , $f = 1.0\text{MHz}$ , $I_E = 0$                                                                                                                                                                                                                                                                                                                   |
| Input Capacitance                    | $C_{ibo}$     | —                                       | 25                                | pF                  | $V_{EB} = 0.5\text{V}$ , $f = 1.0\text{MHz}$ , $I_C = 0$                                                                                                                                                                                                                                                                                                                  |
| Current Gain-Bandwidth Product       | $f_T$         | 300                                     | —                                 | MHz                 | $V_{CE} = 20\text{V}$ , $I_C = 20\text{mA}$ ,<br>$f = 100\text{MHz}$                                                                                                                                                                                                                                                                                                      |
| Noise Figure                         | NF            | —                                       | 4.0                               | dB                  | $V_{CE} = 10\text{V}$ , $I_C = 100\mu\text{A}$ ,<br>$R_S = 1.0\text{k}\Omega$ , $f = 1.0\text{kHz}$                                                                                                                                                                                                                                                                       |
| <b>SWITCHING CHARACTERISTICS</b>     |               |                                         |                                   |                     |                                                                                                                                                                                                                                                                                                                                                                           |
| Delay Time                           | $t_d$         | —                                       | 10                                | ns                  | $V_{CC} = 30\text{V}$ , $I_C = 150\text{mA}$ ,<br>$V_{BE(off)} = -0.5\text{V}$ , $I_{B1} = 15\text{mA}$                                                                                                                                                                                                                                                                   |
| Rise Time                            | $t_r$         | —                                       | 25                                | ns                  |                                                                                                                                                                                                                                                                                                                                                                           |
| Storage Time                         | $t_s$         | —                                       | 225                               | ns                  | $V_{CC} = 30\text{V}$ , $I_C = 150\text{mA}$ ,<br>$I_{B1} = I_{B2} = 15\text{mA}$                                                                                                                                                                                                                                                                                         |
| Fall Time                            | $t_f$         | —                                       | 60                                | ns                  |                                                                                                                                                                                                                                                                                                                                                                           |

Notes: 4. Short duration test pulse used to minimize self-heating effect.

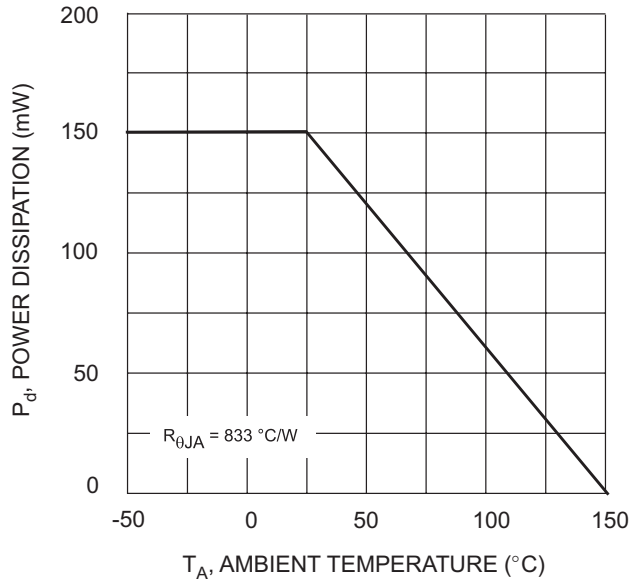


Fig. 1, Derating Curve - Total

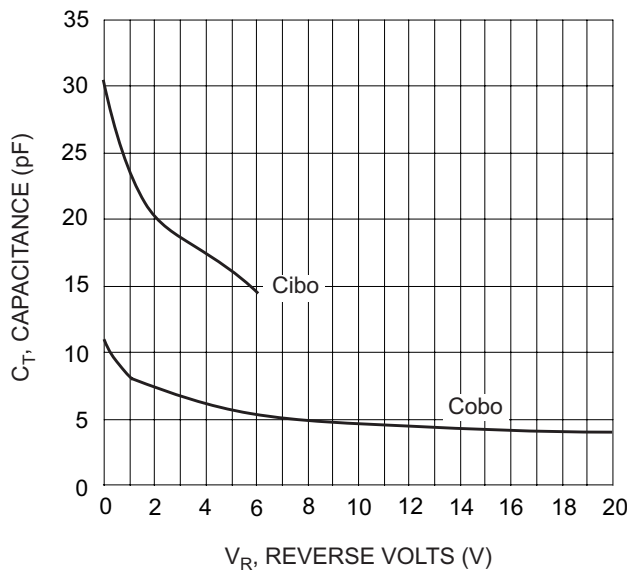


Fig. 3 Typical Capacitance Characteristics

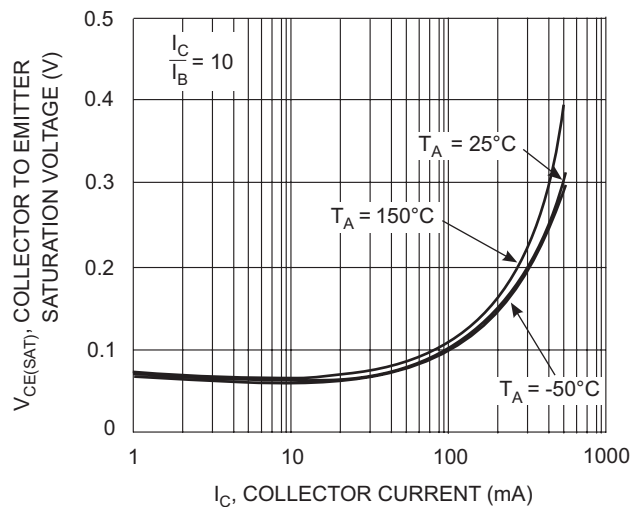


Fig. 5 Collector Emitter Saturation Voltage vs. Collector Current

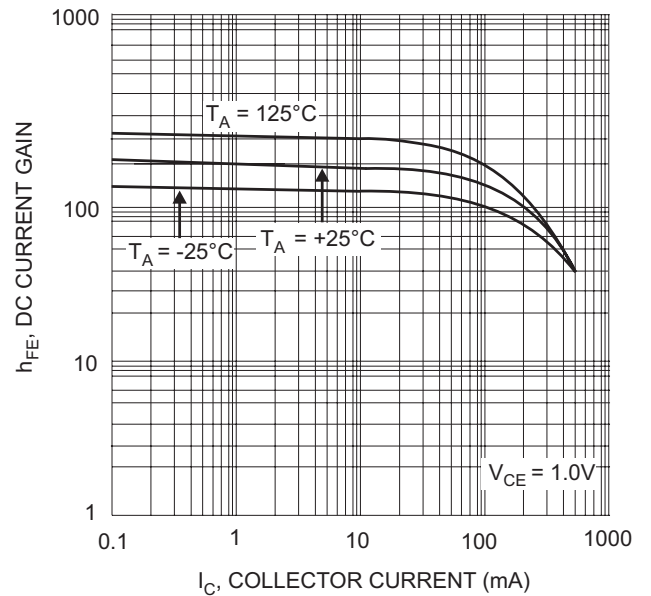


Fig. 2 Typical DC Current Gain vs Collector Current

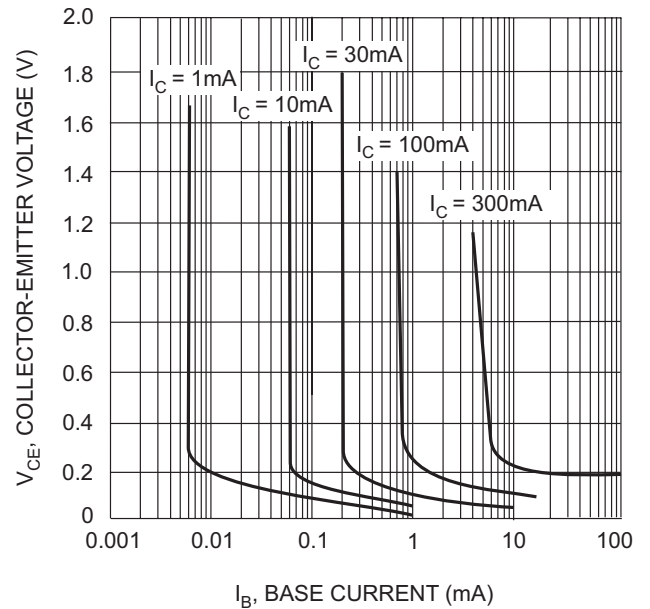


Fig. 4 Typical Collector Saturation Region

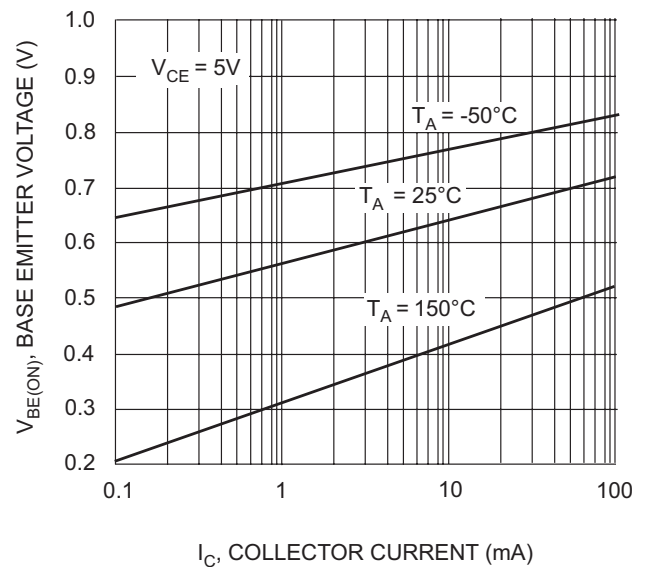


Fig. 6 Base Emitter Voltage vs. Collector Current

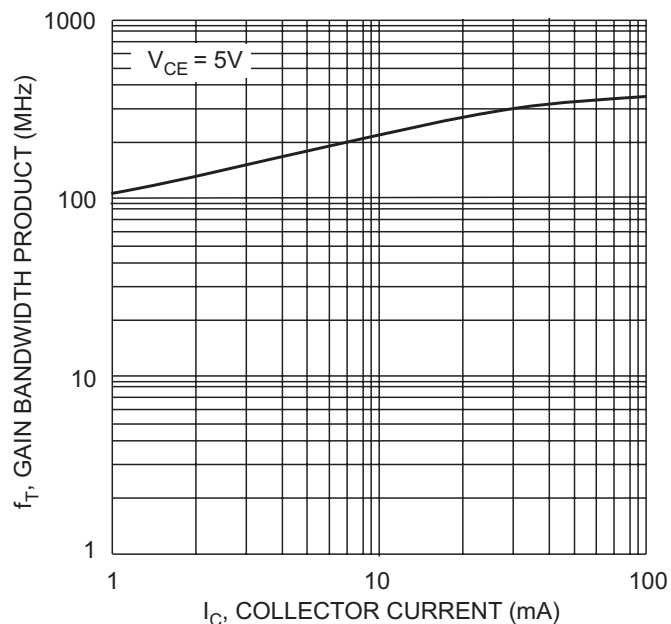


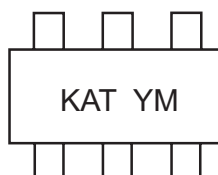
Fig. 7 Gain Bandwidth Product vs. Collector Current

## Ordering Information (Note 5)

| Device      | Packaging | Shipping         |
|-------------|-----------|------------------|
| MMDT2222V-7 | SOT-563   | 3000/Tape & Reel |

Notes: 5. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

## Marking Information



KAT = Product Type Marking Code  
 YM = Date Code Marking  
 Y = Year ex: R = 2004  
 M = Month ex: 9 = September

### Date Code Key

| Year |  |  |  |  |  |  | 2004 | 2005 | 2006 | 2007 | 2008 | 2009 |
|------|--|--|--|--|--|--|------|------|------|------|------|------|
| Code |  |  |  |  |  |  | R    | S    | T    | U    | V    | W    |

| Month | Jan | Feb | March | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|-------|-----|-----|-------|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| Code  | 1   | 2   | 3     | 4   | 5   | 6   | 7   | 8   | 9   | O   | N   | D   |